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**ZXTD6717E6**

**COMPLEMENTARY 15V NPN & 12V PNP LOW SATURATION TRANSISTORS IN SOT26**

**Features and Benefits**

- Pd = 1.1W in SOT26 Package
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

**NPN Transistor**

- $BV_{CEO} > 15V$
- $I_C = 1.5A$  Continuous Collector Current
- Low Saturation Voltage (100mV max @ 1A)
- $R_{SAT} = 135m\Omega @ 1.5A$  for a Low Equivalent On-Resistance

**PNP Transistor**

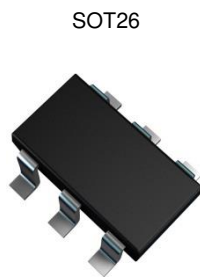
- $BV_{CEO} > -12V$
- $I_C = -1.25A$  Continuous Collector Current
- Low Saturation Voltage (-140mV max @ -1A)
- $R_{SAT} = 150m\Omega @ 1.2A$  for a Low Equivalent On-Resistance

**Mechanical Data**

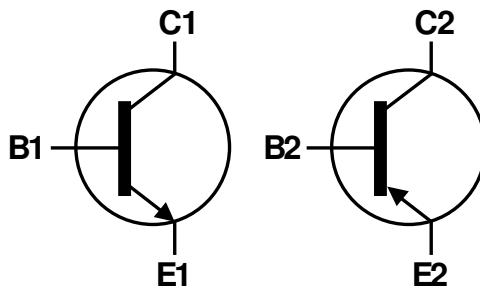
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.015 grams (Approximate)

**Applications**

- Efficient Driving Functions including Motors, Lamps, Relays and Solenoids
- High Output Current Switches

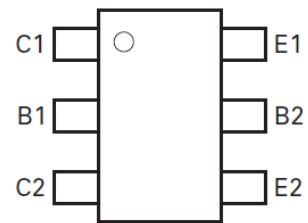


Top View



NPN Transistor

PNP Transistor



Top View Pin-Out

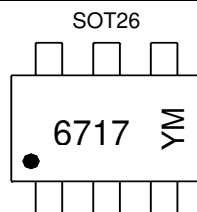
Device Symbol

**Ordering Information** (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTD6717E6TA	AEC-Q101	6717	7	8	3,000
ZXTD6717E6QTA	Automotive	6717	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to [http://www.diodes.com/quality/product\\_compliance\\_definitions/](http://www.diodes.com/quality/product_compliance_definitions/).
  5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**



6717 = Product Type Marking Code  
 YM = Date Code Marking  
 Y or  $\bar{Y}$  = Year (ex: C = 2015)  
 M or  $\bar{M}$  = Month (ex: 9 = September)

**Date Code Key**

Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	C	D	E	F	G	H	I	J	K	L	M

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**NPN - Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	15	V
Collector-Emitter Voltage	V <sub>CEO</sub>	15	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Peak Pulse Current	I <sub>CM</sub>	5	A
Continuous Collector Current	I <sub>C</sub>	1.5	A
Base Current	I <sub>B</sub>	200	mA

**PNP - Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-12	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-12	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Peak Pulse Current	I <sub>CM</sub>	-3	A
Continuous Collector Current	I <sub>C</sub>	-1.25	A
Base Current	I <sub>B</sub>	-200	mA

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P <sub>D</sub>	1.1	W
		8.8	
		1.7	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	13.6	mW/°C
		125	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	45	°C/W
		95	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
6. For a device mounted with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; the device is measured under still air conditions whilst operating in a steady-state. Two active dice running at equal power with heatsink split 50% to each collector.
  7. Same as Note 6, except the device is measured at t < 5 seconds.
  8. Thermal resistance from junction to solder-point (at the end of the collector lead).
  9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

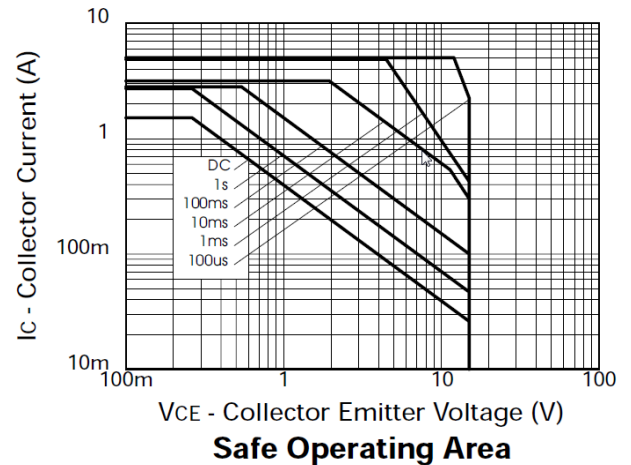
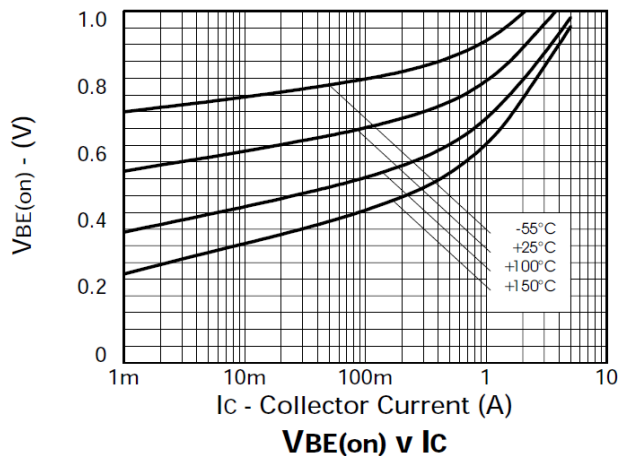
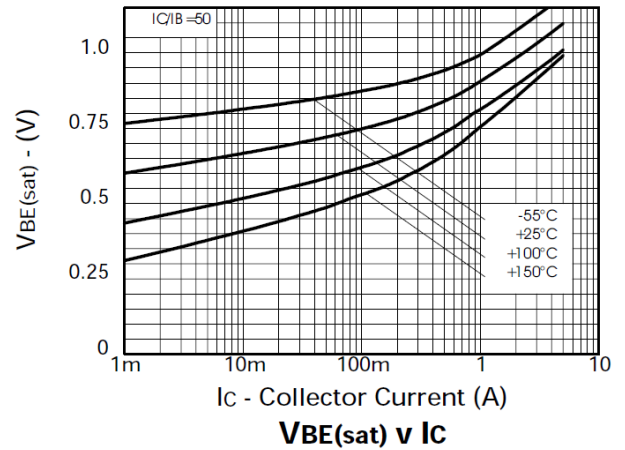
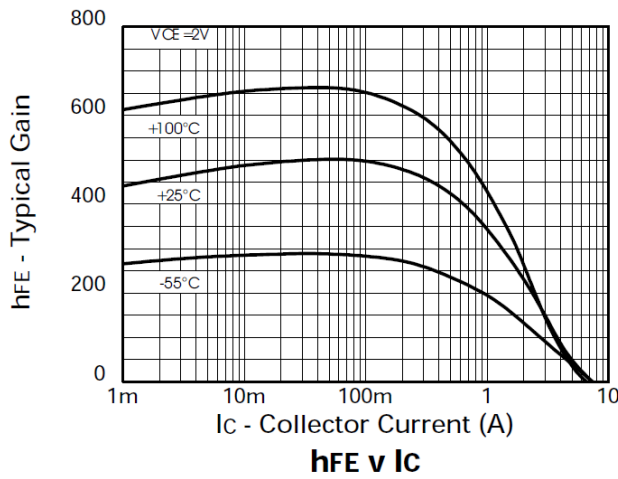
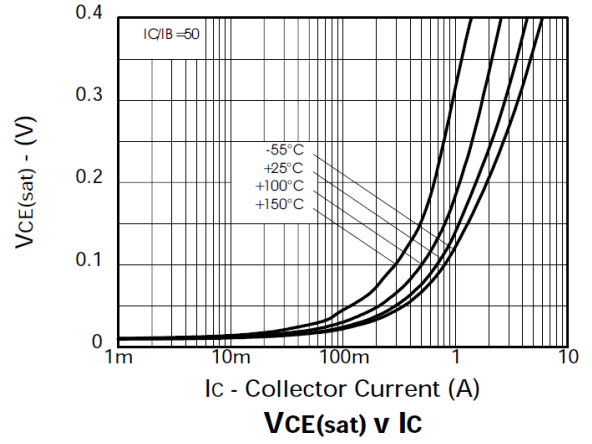
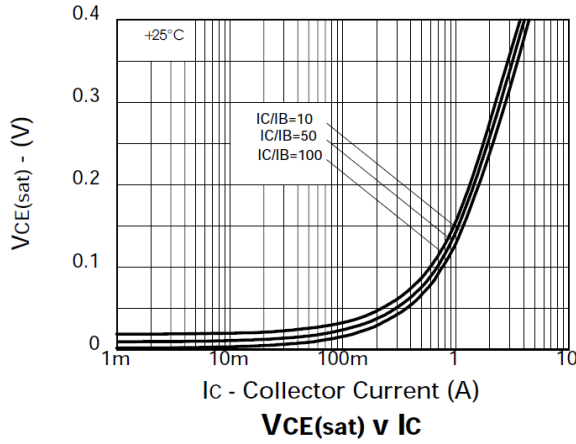


**NPN - Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	15	—	—	V	I <sub>C</sub> = 100μA, I <sub>E</sub> = 0
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	15	—	—	V	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	—	—	V	I <sub>E</sub> = 100μA, I <sub>C</sub> = 0
Collector Cut-Off Current	I <sub>CBO</sub>	—	<-1	10	nA	V <sub>CB</sub> = 10V
Emitter Cut-Off Current	I <sub>EBO</sub>	—	<-1	10	nA	V <sub>EB</sub> = 5.6
Emitter Cut-Off Current	I <sub>CES</sub>	—	<-1	10	nA	V <sub>CE</sub> = 10V
<b>ON CHARACTERISTICS (Note 10)</b>						
DC Current Gain	h <sub>FE</sub>	200	420	—	—	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 2V
		300	450	—		I <sub>C</sub> = 100mA, V <sub>CE</sub> = 2V
		250	390	—		I <sub>C</sub> = 500mA, V <sub>CE</sub> = 2V
		200	300	—		I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
		75	150	—		I <sub>C</sub> = 3A, V <sub>CE</sub> = 2V
30	75	—	I <sub>C</sub> = 5A, V <sub>CE</sub> = 2V			
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	16.5	20	mV	I <sub>C</sub> = 100mA, I <sub>B</sub> = 10mA
		—	40	55	mV	I <sub>C</sub> = 250mA, I <sub>B</sub> = 10mA
		—	75	100	mV	I <sub>C</sub> = 500mA, I <sub>B</sub> = 10mA
		—	150	200	mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 10mA
		—	205	245	mV	I <sub>C</sub> = 1.5A, I <sub>B</sub> = 20mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	0.93	1.10	V	I <sub>C</sub> = 1.5A, I <sub>B</sub> = 20mA
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	—	0.865	1.10	V	I <sub>C</sub> = 1.5A, V <sub>CE</sub> = 2V
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Output Capacitance	C <sub>obo</sub>	—	15	—	pF	V <sub>CB</sub> = 10V, f = 1.0MHz
Current Gain Bandwidth Product	f <sub>T</sub>	—	180	—	MHz	I <sub>C</sub> = 50mA, V <sub>CE</sub> = 10V f = 100MHz
<b>SWITCHING CHARACTERISTICS</b>						
Turn-On Time	t <sub>on</sub>	—	50	—	ns	I <sub>C</sub> = 1A, V <sub>CC</sub> = 10V
Turn-Off Time	t <sub>off</sub>	—	250	—	ns	I <sub>B1</sub> = -I <sub>B2</sub> = 100mA

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**NPN - Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

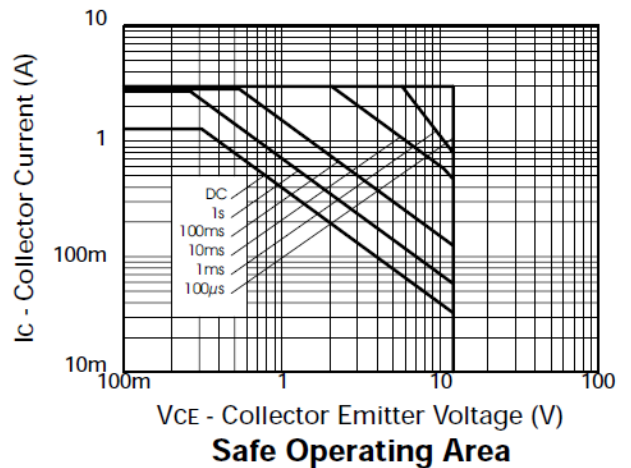
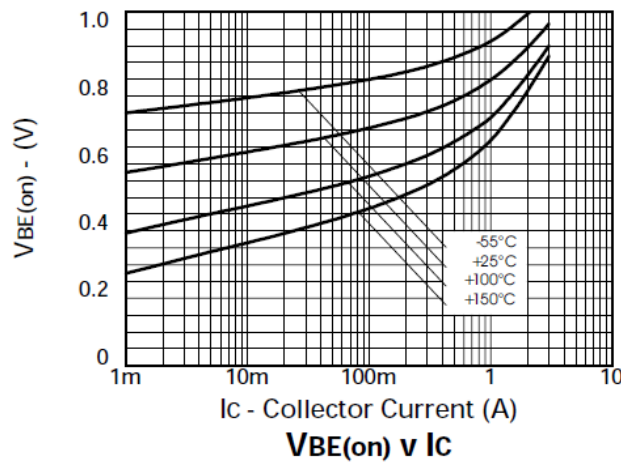
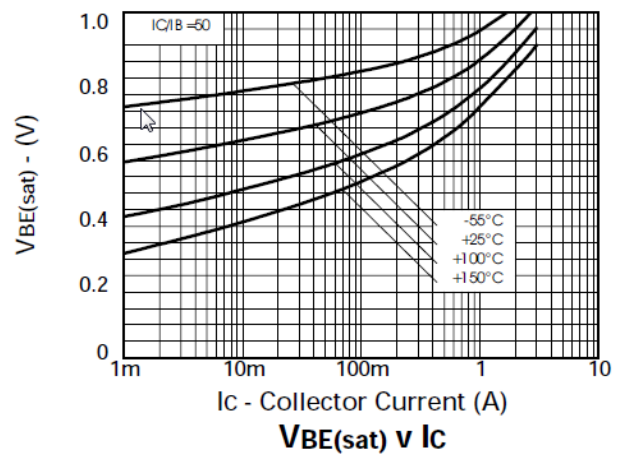
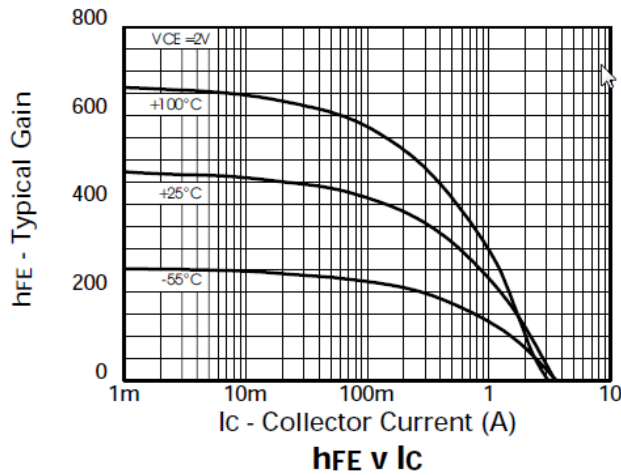
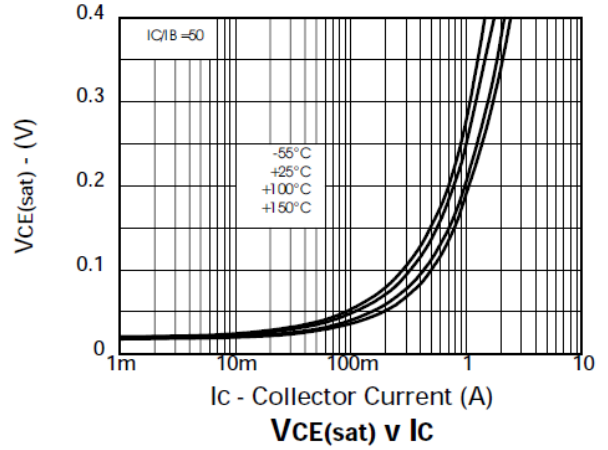
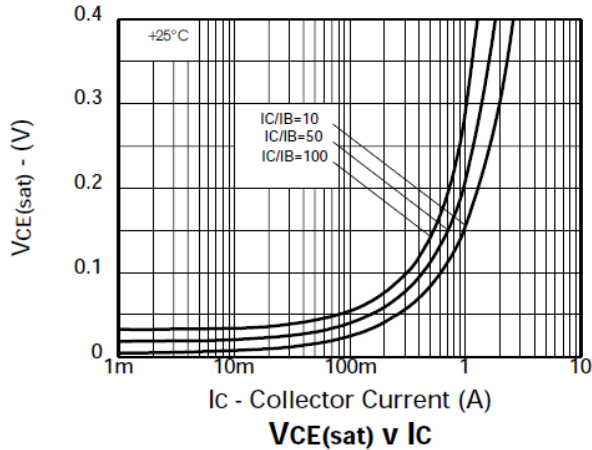


**PNP - Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-12	—	—	V	I <sub>C</sub> = -100μA, I <sub>E</sub> = 0
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-12	—	—	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	—	—	V	I <sub>E</sub> = -100μA, I <sub>C</sub> = 0
Collector Cut-Off Current	I <sub>CBO</sub>	—	<-1	-10	nA	V <sub>CB</sub> = -10V
Emitter Cut-Off Current	I <sub>EBO</sub>	—	<-1	-10	nA	V <sub>EB</sub> = -5.6V
Emitter Cut-Off Current	I <sub>CES</sub>	—	<-1	-10	nA	V <sub>CE</sub> = -10V
<b>ON CHARACTERISTICS (Note 11)</b>						
DC Current Gain	h <sub>FE</sub>	300	490	—	—	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V
		300	450	—		I <sub>C</sub> = -100mA, V <sub>CE</sub> = -2V
		200	340	—		I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
		125	250	—		I <sub>C</sub> = -1.25A, V <sub>CE</sub> = -2V
		75	140	—		I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V
30	80	—	I <sub>C</sub> = -3A, V <sub>CE</sub> = -2V			
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	-25	-40	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA
		—	-55	-100	mV	I <sub>C</sub> = -250mA, I <sub>B</sub> = -10mA
		—	-110	-175	mV	I <sub>C</sub> = -500mA, I <sub>B</sub> = -10mA
		—	-160	-215	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA
		—	-185	-240	mV	I <sub>C</sub> = -1.25A, I <sub>B</sub> = -100mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	-0.99	-1.10	V	I <sub>C</sub> = -1.25A, I <sub>B</sub> = -100mA
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	—	-0.85	-1.0	V	I <sub>C</sub> = -1.25A, V <sub>CE</sub> = -2V
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Output Capacitance	C <sub>obo</sub>	—	15	—	pF	V <sub>CB</sub> = -10V, f = 1.0MHz
Current Gain Bandwidth Product	f <sub>T</sub>	—	220	—	MHz	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V f = 100MHz
<b>SWITCHING CHARACTERISTICS</b>						
Turn-On Time	t <sub>on</sub>	—	50	—	ns	I <sub>C</sub> = -1A, V <sub>CC</sub> = -10V
Turn-Off Time	t <sub>off</sub>	—	135	—	ns	I <sub>B1</sub> = -I <sub>B2</sub> = -100mA

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

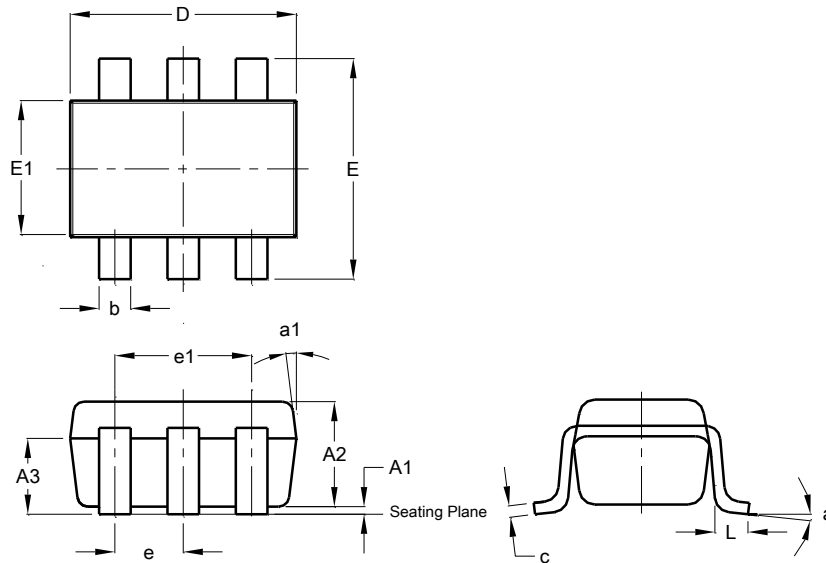
**PNP - Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**ZXTD6717E6**

### Package Outline Dimensions

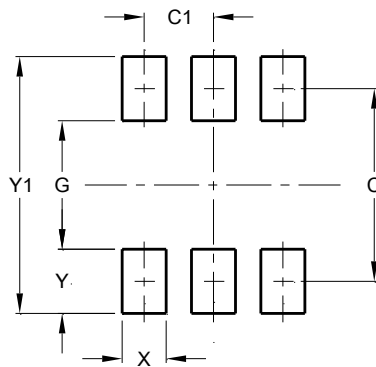
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT26			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	-	-	8°
a1	-	-	7°
All Dimensions in mm			

### Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.40
C1	0.95
G	1.60
X	0.55
Y	0.80
Y1	3.20



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